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CONFIRMATION NO. 8834

<b>SERIAL NUMBER</b> 10/538,878	<b>FILING OR 371(c) DATE</b> 06/14/2005 <b>RULE</b>	<b>CLASS</b> 117	<b>GROUP ART UNIT</b> 1722	<b>ATTORNEY DOCKET NO.</b> 124231	
<b>APPLICANTS</b> Masahiro Sakurada, Fukushima, JAPAN; Izumi Fusegawa, Fukushima, JAPAN;  <b>** CONTINUING DATA *****</b> This application is a 371 of PCT/JP03/16794 12/25/2003  <b>** FOREIGN APPLICATIONS *****</b> JAPAN 2003-10436 01/17/2003					
Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no 35 USC 119 (a-d) conditions <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after met Verified and <i>A. Fusegawa</i> Acknowledged <i>Elk</i> Examiner's Signature Initials		<b>STATE OR COUNTRY</b> JAPAN	<b>SHEETS DRAWING</b> 4	<b>TOTAL CLAIMS</b> 28	<b>INDEPENDENT CLAIMS</b> 2
<b>ADDRESS</b> 25944					
<b>TITLE</b> Process for producing p doped silicon single crystal and p doped n type silicon single crystal wafer					
<b>FILING FEE RECEIVED</b> 1300	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:		<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees ( Filing ) <input type="checkbox"/> 1.17 Fees ( Processing Ext. of time ) <input type="checkbox"/> 1.18 Fees ( Issue ) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit		